

SJ

**INDUSTRY STANDARD OF THE
PEOPLE'S REPUBLIC OF CHINA**

SJ/T 11849-2022

**Semiconductor discrete devices 3DG3500, 3DG3501 type NPN
silicon high-frequency low-power transistor detailed
specification**

半导体分立器件3DG3500、3DG3501型NPN硅高频小功率晶体管详细规范
(English Translation)

Issued on: September 30, 2022

Implemented on: January 1, 2023

Issued by: Ministry of Industry and Information Technology

Table of Contents

What this standard covers	1
Document data	2

What this standard covers

This standard specifies the appearance, limit value, electrical characteristics and assessment requirements of 3DG3500 and 3DG3501 products.

Document data

Estimated length of the Chinese original: 15,117 words.